



Ultrafast Plastic Rectifier

Major Ratings and Characteristics

I _{F(AV)}	3.0 A
V _{RRM}	600 V
I _{FSM}	90 A
t _{rr}	30 ns
V _F	1.6 V
T _j max.	150 °C



Features

- · Glass passivated chip junction
- · Ultrafast reverse recovery time
- · Low forward voltage drop
- · Low switching losses, high efficiency
- High forward surge capability
- Solder Dip 260 °C, 40 seconds



Typical Applications

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer, computer and Telecommunication

Mechanical Data

Case: DO-201AD

Epoxy meets UL-94V-0 Flammability rating Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D E3 suffix for commercial grade

Polarity: Color band denotes cathode end

Maximum Ratings

 $T_A = 25$ °C unless otherwise specified

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	600	V
Maximum RMS voltage	V _{RMS}	420	V
Maximum DC blocking voltage	V _{DC}	600	V
Maximum average forward rectified current, 0.375" (9.5 mm) lead length at $T_L = 110 ^{\circ}\text{C}$	I _{F(AV)}	3.0	А
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	90	A
Operating junction and storage temperature range	T _J , T _{STG}	- 40 to + 150	°C
Reverse Avalanche Energy (8/20 μs surge)	E _{AR}	10	mJ

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Electrical Characteristics

 $T_A = 25$ °C unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Minimum reverse breakdown voltage	at 10 μA	$V_{(BR)}$	600	V
Maximum instantaneous forward voltage	at 3.0 A ⁽¹⁾	V _F	1.6	V
Maximum DC reverse current at rated DC blocking voltage		I _R	20	μА
Maximum reverse recovery time	at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	30	ns

Thermal Characteristics

 $T_A = 25$ °C unless otherwise specified

Paramet	er	Symbol	Value	Unit
Typical thermal resistance ⁽¹⁾	Junction-to-ambient Junction-to-lead	R _{θJA} R _{θJL}	30 8.0	°C/W

Notes:

(1) Pulse test: 300 μ s pulse width, 1 % duty cycle

Ratings and Characteristics Curves

 $(T_A = 25 \, ^{\circ}C \text{ unless otherwise noted})$

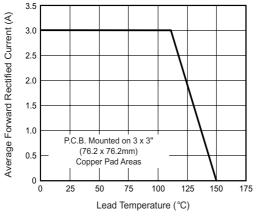


Figure 1. Maximum Forward Current Derating Curve

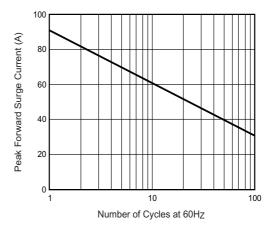


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

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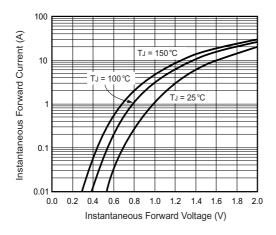


Figure 3. Typical Forward Voltage

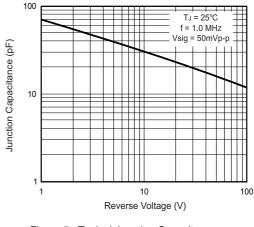


Figure 5. Typical Junction Capacitance

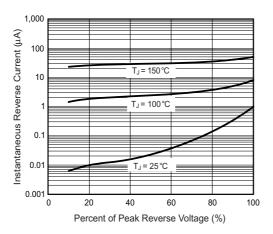
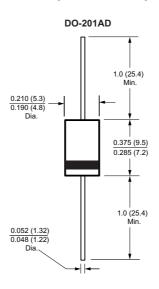


Figure 4. Typical Reverse Current

Package outline dimensions in inches (millimeters)



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